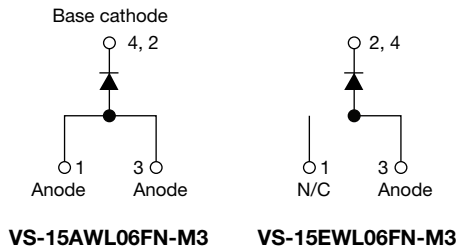


Ultralow V_F Ultrafast Rectifier, 15 A FRED Pt[®]

DPAK (TO-252AA)

FEATURES

- Ultrafast recovery time, extremely low V_F and soft recovery
- 175 °C maximum operating junction temperature
- For PFC DCM operation
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE
DESCRIPTION / APPLICATIONS

State of the art, ultralow V_F , soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	15 A
V_R	600 V
V_F at I_F	0.85 V
t_{rr} (typ.)	60 ns
T_J max.	175 °C
Package	DPAK (TO-252AA)
Circuit configuration	Single

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 148\text{ °C}$	15	A
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$	180	
Peak repetitive forward current	I_{FM}	$T_C = 148\text{ °C}, f = 20\text{ kHz}, d = 50\%$	30	
Operating junction and storage temperatures	T_J, T_{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 15\text{ A}$ $I_F = 15\text{ A}, T_J = 150\text{ °C}$	-	0.99 0.85	1.05 0.92	
Reverse leakage current	I_R	$V_R = V_R$ rated $T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	10 120	μA
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	11	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8	-	nH



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	I _F = 1 A, di _F /dt = 100 A/μs, V _R = 30 V	-	60	120	ns
		I _F = 15 A, di _F /dt = 100 A/μs, V _R = 30 V	-	190	-	
		T _J = 25 °C	-	220	-	
		T _J = 125 °C	-	290	-	
Peak recovery current	I _{RRM}	T _J = 25 °C	-	21	-	A
		T _J = 125 °C	-	25	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C	-	2.6	-	μC
		T _J = 125 °C	-	4	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	1.4	1.8	°C/W
Thermal resistance, junction to ambient	R _{thJA}		-	-	70	
Approximate weight				0.3		g
				0.01		oz.
Marking device		Case style DPAK (TO-252AA)		15AWL06FN		
				15EWL06FN		

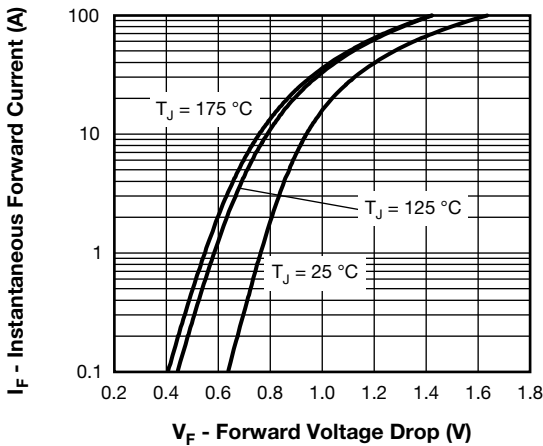


Fig. 1 - Typical Forward Voltage Drop Characteristics

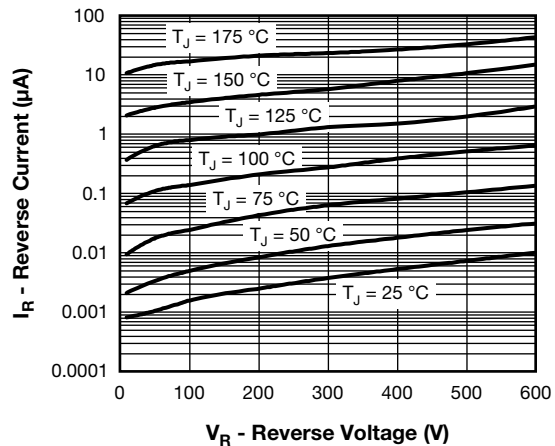


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

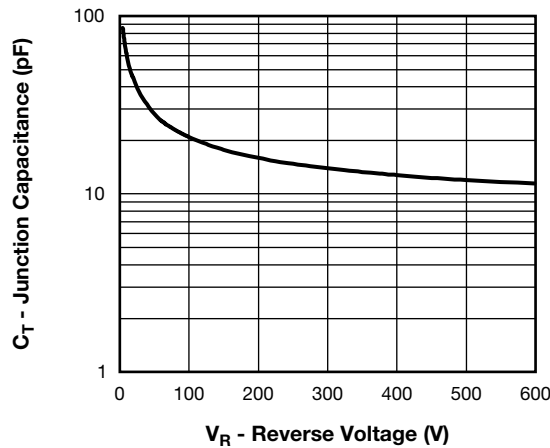


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

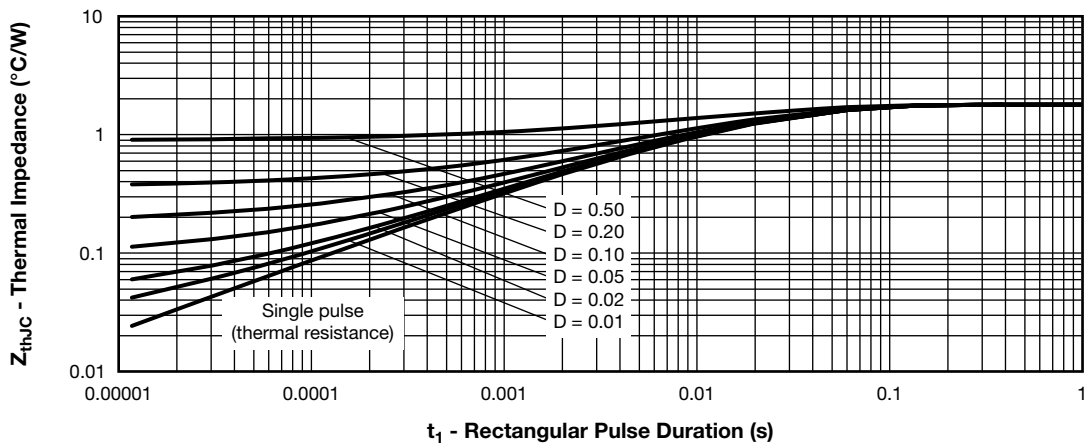


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

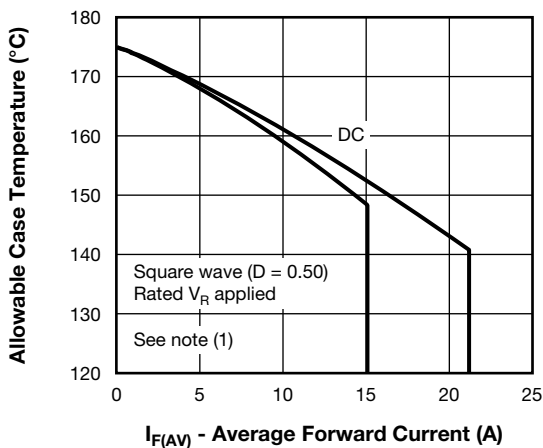


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

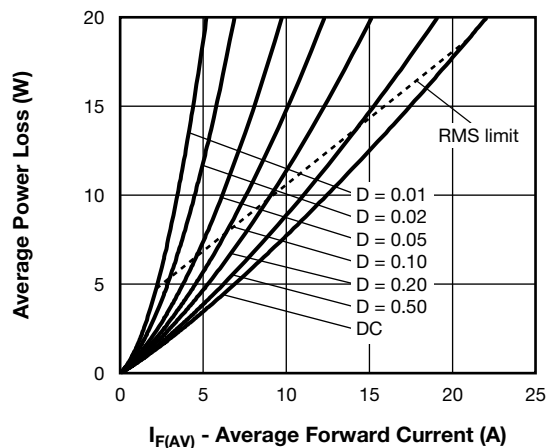


Fig. 6 - Forward Power Loss Characteristics

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
- P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

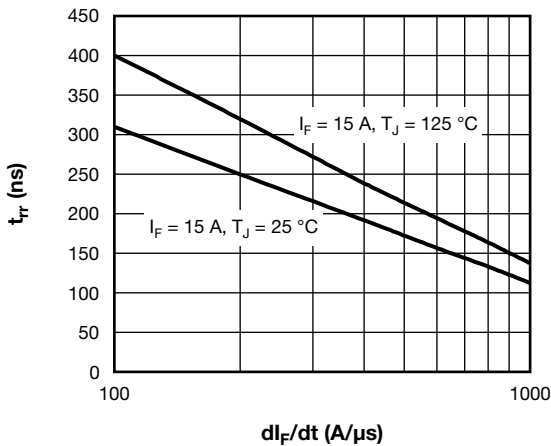


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

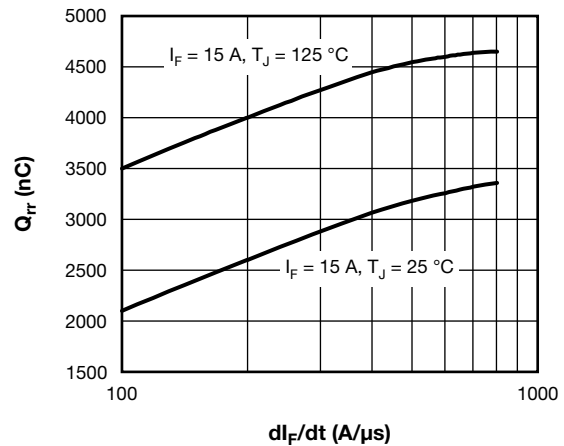
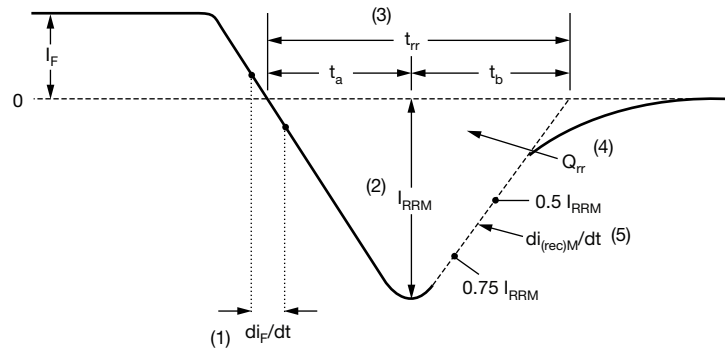


Fig. 8 - Typical Stored Charge vs. di_F/dt



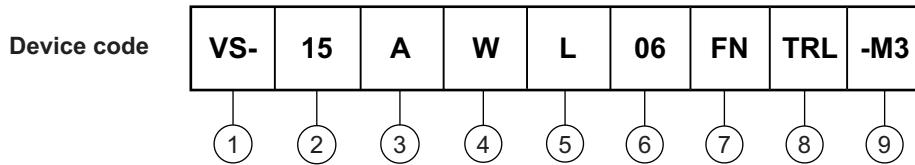
- (1) di_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}
- (5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE



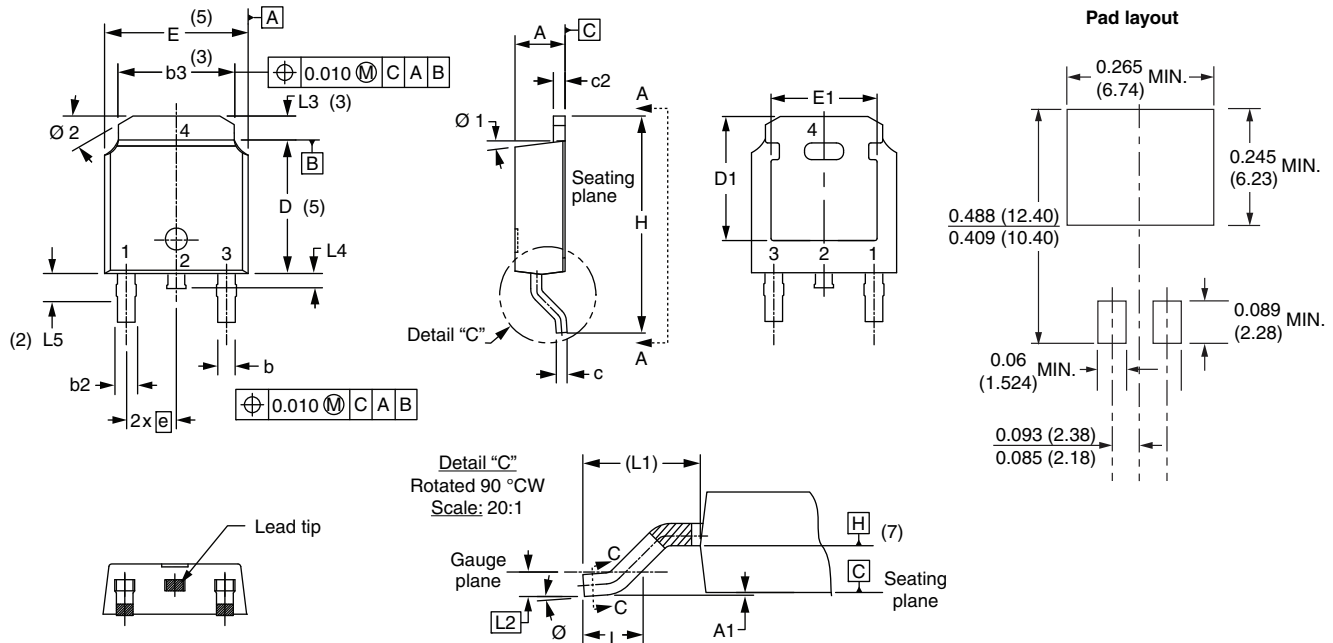
- 1** - Vishay Semiconductors product
- 2** - Current rating (15 = 15 A)
- 3** - Circuit configuration:
 - A = single diode (2 anodes)
 - E = single diode
- 4** - Package identifier:
 - W = DPAK
- 5** - L = hyperfast rectifier
- 6** - Voltage rating (06 = 600 V)
- 7** - FN = TO-252AA
- 8** -
 - None = tube
 - TR = tape and reel
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9** - Environmental digit:
 - M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-15AWL06FN-M3	75	Antistatic plastic tube
VS-15EWL06FN-M3		
VS-15AWL06FNTR-M3	2000	13" diameter reel
VS-15EWL06FNTR-M3		
VS-15AWL06FNTRL-M3	3000	13" diameter reel
VS-15EWL06FNTRL-M3		
VS-15AWL06FNTRR-M3	3000	13" diameter reel
VS-15EWL06FNTRR-M3		

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95627
Part marking information	www.vishay.com/doc?95176
Packaging information	www.vishay.com/doc?95033
SPICE model	www.vishay.com/doc?95372

D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	2.18	2.39	0.086	0.094		e	2.29 BSC		0.090 BSC		
A1	-	0.13	-	0.005		H	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045		L1	2.74 BSC		0.108 REF.		
b3	4.95	5.46	0.195	0.215	3	L2	0.51 BSC		0.020 BSC		
c	0.46	0.61	0.018	0.024		L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035		L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3	Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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